Valid from 2024.HS

| Module description: Electronics 2 | | | | | | |
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| Module Code | t.BA.ET.EK2.19HS | | | | | |
| ECTS Credits | 4 | | | | | |
| Language of Instruction/Examination | German | | | | | |
| Organizational Unit | ISC Signal & WCOM | | | | | |
| Module Coordinator | Teddy Loeliger | | | | | |
| Legal Framework | The module description is part of the legal basis in addition to the general academic regulations. It is binding. During the first week of the semester a written and communicated supplement can specify the module description in more detail. | | | | | |
| Module Characteristic | Type 3a | | | | | |
| | 2 lecture lessons per semester week and class+ 2 lab bi-weekly lessons per semester and half-class | | | | | |
| Module Description | Students acquire the knowledge and skills required for the understanding, analysis and design of standard electronic circuits with discrete components. This includes a systematic approach to the calculation, simulation and optimisation of modern circuits. | | | | | |
| Module Content | Based on exemplary electronic circuits in modern electronics modules, circuits are identified, analysed, and designed. | | | | | |
| | The module includes the following topics: | | | | | |
| | Bipolar Transistors (principle of operation, characteristics, equivalent circuits) Field-Effect Transistors (principle of operation, characteristics, equivalent circuits) Transistor Amplifier Circuits Current Sources and Current Mirrors Real Operational Amplifiers (structure, non-idealities, differential amplifier) Active Filters (filter theory, filter design, filter implementations) Oscillators (feedback, LC oscillators, RC oscillators, crystal oscillators, multivibrators, ring oscillators) | | | | | |
| Prerequisite Knowledge | Properties and circuits with ideal operational amplifiers Properties of diodes Properties and behavior of field-effect transistors as switches Simulations with LTspice | | | | | |

Module description: Electronics 2

| Learning Objectives | | | | |
|----------------------------|--|--|--|--|
| (Competences) | | | | |

| Students | Competencies | Taxonomies |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|---------------------------|
| You work in teams of two on the setup and analysis of practical electronic circuits and practice the ability to shape interpersonal processes in a situation-specific, goal-oriented and effective manner. | so | K5 |
| You can identify, analyze, dimension, build and test transistor amplifier circuits, current sources, current mirrors, and oscillators. | M, F | K1, K2, K3, K4 |
| You know the basic filter approximations and can calculate, characterize, design and dimension active filters using filter tables. | F, M | K1, K2, K3, K4, K5 |
| You are experienced in working with a circuit simulation tool and can check the simulation output results for plausibility. | М | K3, K6 |
| You know the internal structure of an operational amplifier, its non-idealities, and can design a suitable operational amplifier circuit for a given application. | M, F | K1, K2, K3, K4, K5, K6 |
| You can identify core relations and equations in electronic circuit areas, condense them concisely and apply them to the analysis of circuits. | SE | K4, K5 |
| You know the characteristics of bipolar and field-effect transistors and can determine these properties by measurements and compare them with the data sheet information. | F, M | K1, K2, K3 |

Performance Assessment

| End-of-module exam | Assessment | Length (min.) | Weighting | Form |
|--------------------|------------|------------------|-----------|--------------------------|
| written exam | Grade | 90 | 80 | acc. to module agreement |

| Performance assessment during the semester | Assessment | Length (min.) | Weighting | Form |
|--------------------------------------------|------------|------------------|-----------|--------------------------------|
| written exam | Grade | 40 | 20 | acc. to module agreement |

Classroom Attendance Requirement

None

Learning material

- Exercises (for self-study)
- Lecture slides
- Lab instructions

Comments

Resources in the laboratory:

- Circuit simulation tool (LTspice)
- Laboratory infrastructure (electronic setups, measurement instruments)